NSN 5961-00-900-0063

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-00-900-0063 **Inclosure Material:** Metal **Overall Length:** 0.360 inches **Overall Diameter:** 1.220 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Germanium Voltage Rating In Volts Per Characteristic: 45.0 breakdown voltage, collector-to-base, emitter open and 25.0 breakdown voltage, emitter-to-base, collector open and 30.0 breakdown voltage, collector-to-emitter, base open **Current Rating Per Characteristic:** 30.00 amperes source cutoff current and 4.00 milliamperes zero-gate-voltage source current preset **Power Rating Per Characteristic:** 170.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Thread Series Designator:** Unf **Terminal Type And Quantity:** 1 case and 2 tab, solder lug **Specification Data:** 80131-release3374 professional/industrial association specification Shelf Life: N/a **Unit Of Measure:**

No

Demilitarization:

NSN 5961-00-900-0063 Transistor - Page 2 of 2



Fiig:

A110a0